



RSD200N05TL Information



For Reference Only

Part Number RSD200N05TL

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 45V 20A CPT3

Package TO-252-3, DPak (2 Leads + Tab), SC-63

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RSD200N05TL Specifications

Manufacturer Part Number Manufacturer Category Discrete Semiconductor Transistors - FETs, MOSFETs - Single Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Drive Voltage (Max Rds On, Min Rds On) RSD200N05TL Rohm Semiconductor Products Transistors - FETs, MOSFETs - Single NOSFETs - Single Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series - FET Type N-Channel MOSFET (Metal Oxide) 45V Current - Continuous Drain (Id) @ 25°C 20A (Ta) 4V, 10V	
Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single N-Channel N-Channel MOSFET (Metal Oxide) 20A (Ta)	
Transistors - FETs, MOSFETs - Single Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Transistors - FETs, MOSFETs - Single To-252-3, DPak (2 Leads + Tab), SC-63 WOSFET (Metal Oxide) 45V Current - Continuous Drain (Id) @ 25°C	
Package TO-252-3, DPak (2 Leads + Tab), SC-63 Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 45V Current - Continuous Drain (Id) @ 25°C 20A (Ta)	
Series - N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 45V Current - Continuous Drain (Id) @ 25°C 20A (Ta)	
FET Type Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C N-Channel MOSFET (Metal Oxide) 250 (Ta)	
Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 45V Current - Continuous Drain (Id) @ 25°C 20A (Ta)	
Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 20A (Ta)	
Current - Continuous Drain (Id) @ 25°C 20A (Ta)	
Drive Voltage (Max Rds On, Min Rds On) 4V, 10V	
Vgs(th) (Max) @ Id 2.5V @ 1mA	
Gate Charge (Qg) (Max) @ Vgs 12nC @ 5V	
Input Capacitance (Ciss) (Max) @ Vds 950pF @ 10V	
Vgs (Max) ±20V	
FET Feature -	
Power Dissipation (Max) 20W (Tc)	
Rds On (Max) @ Id, Vgs 28 mOhm @ 20A, 10V	
Operating Temperature 150°C (TJ)	
Mounting Type Surface Mount	
Supplier Device Package CPT3	
Package / Case TO-252-3, DPak (2 Leads + Tab), SC-63	
	Report errors?

RSD200N05TL Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RSD200N05TL Payment Methods



















RSD200N05TL Shipping Methods













If you have any question about RSD200N05TL, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com